DACO SEMICONDUCTOR CO., LTD. CSRI2×140-120P1B

SIC SCHOTTKY DIODE TYPE 2×140A

Preliminary

SOT-227

Features

- High surge current capable
- Zero reverse recovery current · VDC
- High bandwidth
- Isolation type package

Benefits

- Unipolar rectifier
- Zero switching loss
- Higher efficiency

Applications

- Motor drives
- Switch mode power supplies
- Ev chargers
- Solar inverters
- Welding equipment

- Temperature Independent Switching Behavior
 - /DC 1200 V
- I_F (Tc<135°C) 2×140 A
- Smaller heat sink
- Parallel devices without thermal runaway
- Power factor correction
- Diode snubber
- Automotive
- induction heating

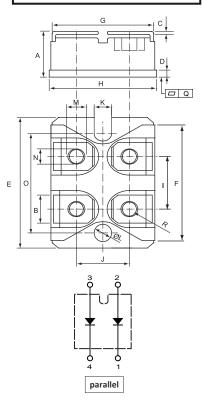
Maximum Ratings

Operating Junction Temperature : - 55 $^\circ\!C$ to +175 $^\circ\!C$

Storage Temperature : -55 $^\circ\!C$ to +175 $^\circ\!C$

Part Number	Maximum Recurrent Peak Reverse Voltage	Maximum DC Blocking Voltage
CSRI2×140-120P1B	1200V	1200V

Maximum Rating	Symbol	Conditions	Value	Unit	
Continuous forward current (per diode)	I _F	T _C =135 °C	140		
Surge non-repetitive forward current	I _{FSM}	T _C =25 °C, t _p =8.3 ms	1000		
sine halfwave (per diode)	-FSIM	T _C =150 °C, t _p =8.3 ms	600	А	
Non-repetitive peak forward current	I _{F,max}	T _C =25 °C, t _p =10 μ s	4200		
(per diode)	IF,max	T _C =150 °C, t _p =10 μ s	2600		
Repetitive peak reverse voltage	V_{RRM}	T _j =25 °C	1200	V	
Isolation voltage between all terminals and baseplate	V _{iso}	50/60 Hz, t=1min I _{ISOL} ≤ 1mA	2500	V	
Mounting torque		To heatsink	1.3	Nm	
		To terminal	1.1		



DIMENSIONS					
	INCHES		MM		
	MIN	MAX	MIN	MAX	
А	0.460	0.483	11.68	12.28	
В	0.307	0.323	7.80	8.20	
С	0.030	0.033	0.75	0.85	
D	0.071	0.081	1.80	2.05	
E	1.488	1.504	37.80	38.20	
F	1.248	1.260	31.70	32.00	
G	0.917	0.957	23.30	24.30	
Н	0.996	1.008	25.30	25.60	
Ι	0.579	0.602	14.70	15.30	
J	0.492	0.516	12.50	13.10	
K	0.161	0.169	4.10	4.30	
L	0.161	0.169	4.10	4.30	
М	0.181	0.197	4.60	5.00	
Ν	0.165	0.181	4.20	4.60	
0	1.181	1.197	30.00	30.40	
Q	-0.002	0.004	-0.05	0.10	
R	M4*8				

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Electrical Characteristics, at T_i=25 °C, unless otherwise specified. (per diode)

Static Characteristics	Symbol	Conditions	Values			
			min.	typ.	max.	Unit
DC blocking voltage	V_{DC}		1,200	-	-	
Diode forward voltage	V _F	I _F =140A, T _j =25 °C	-	1.6	1.8	V
		I _F =140A, T _j =175 °C	-	2.4	2.9	
	1-	V _R =1,200V, T _j =25 °C	-	80	150	
Reverse current	IR	V _R =1,200V, T _j =175 °C	-	150	500	μΑ

AC Characteristics (per diode)

Static Characteristics	Symbol	Conditions	Values			
			min.	typ.	max.	Unit
Total capacitive charge	Q _{rr}	V _R =800V, T _j =25 °C	-	532	-	nC
Total capacitance	С	V _R =0V, f=1 MHz T _j =25 °C	-	7600	-	pF
		V _R =400V, f=1 MHz T _j =25 °C	-	712	-	
		V _R =800V, f=1 MHz T _j =25 °C	-	568	-	

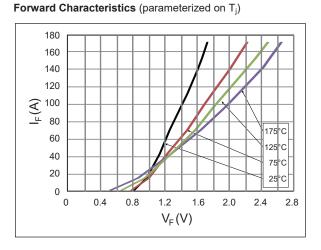
Thermal Characteristics (per diode)

Statia Characteristica	Symphol	Values		
Static Characteristics	Symbol	typ.	Unit	
Thermal resistance from junction to case	$R_{ heta JC}$	0.10	°C/W	

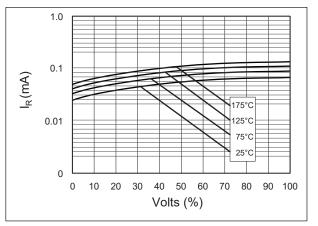
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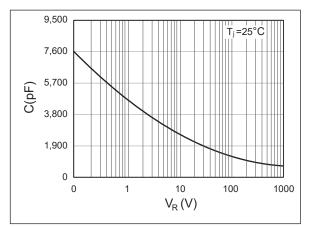
Typical Performance



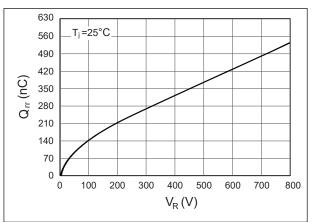
Reverse Characteristics (parameterized on Tj)



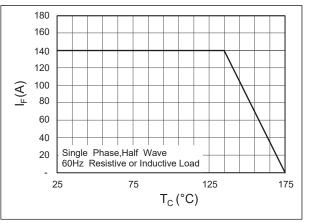
Capacitance



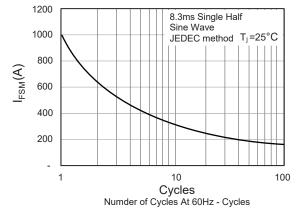
Recovery Charge



Current Derating









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